# MJF44H11 (NPN), **MJF45H11 (PNP)**

Preferred Devices

# Complementary **Power Transistors**

# For Isolated Package Applications

Complementary power transistors are for general purpose power amplification and switching such as output or driver stages in applications such as switching regulators, converters and power amplifiers.

## Features

- Low Collector-Emitter Saturation Voltage -
  - V<sub>CE(sat)</sub> = 1.0 V (Max) @ 8.0 A
- Fast Switching Speeds
- Complementary Pairs Simplifies Designs
- Pb-Free Packages are Available\*

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	80	Vdc
Emitter-Base Voltage	$V_{EB}$	5	Vdc
Collector Current – Continuous – Peak	Ι <sub>C</sub>	10 20	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	36 0.288	W W/°C
Total Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	2.0 0.016	W W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to 150	°C

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	3.5	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	62.5	°C/W

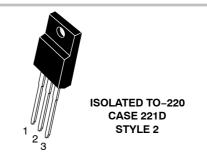
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



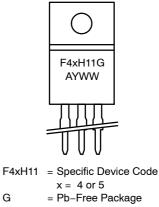
## **ON Semiconductor®**

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SILICON POWER TRANSISTORS **10 AMPERES** 80 VOLTS, 36 WATTS



## **MARKING DIAGRAM**



= Assembly Location

= Year

ww = Work Week

G

А

Y

## **ORDERING INFORMATION**

Device	Package	Shipping
MJF44H11	TO-220 FULLPACK	50 Units/Rail
MJF44H11G	TO-220 FULLPACK (Pb-Free)	50 Units/Rail
MJF45H11	TO-220 FULLPACK	50 Units/Rail
MJF45H11G	TO-220 FULLPACK (Pb-Free)	50 Units/Rail

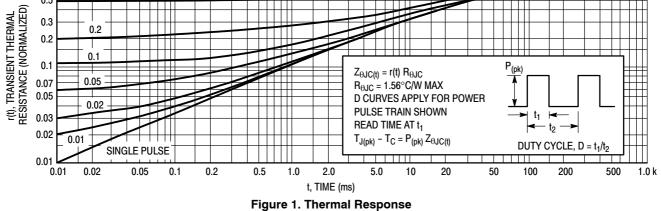
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Preferred devices are recommended choices for future use and best overall value.

## MJF44H11 (NPN), MJF45H11 (PNP)

## **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise noted)

	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS			•		
Collector-Emitter Sustaining Voltage $(I_C = 30 \text{ mA}, I_B = 0)$	V <sub>CEO(sus)</sub>	80	-	-	Vdc
Collector Cutoff Current ( $V_{CE}$ = Rated V <sub>CEO</sub> , V <sub>BE</sub> = 0)	I <sub>CES</sub>	_	-	1.0	μΑ
Emitter Cutoff Current (V <sub>EB</sub> = 5 Vdc)	I <sub>EBO</sub>	-	_	10	μΑ
ON CHARACTERISTICS	·				
Collector–Emitter Saturation Voltage $(I_C = 8 \text{ Adc}, I_B = 0.4 \text{ Adc})$	V <sub>CE(sat)</sub>	-	_	1.0	Vdc
Base–Emitter Saturation Voltage $(I_C = 8 \text{ Adc}, I_B = 0.8 \text{ Adc})$	V <sub>BE(sat)</sub>	_	-	1.5	Vdc
DC Current Gain (V <sub>CE</sub> = 1 Vdc, I <sub>C</sub> = 2 Adc)	h <sub>FE</sub>	60	-	_	-
DC Current Gain (V <sub>CE</sub> = 1 Vdc, I <sub>C</sub> = 4 Adc)		40	-	_	-
DYNAMIC CHARACTERISTICS				1	
Collector Capacitance (V <sub>CB</sub> = 10 Vdc, f <sub>test</sub> = 1 MHz) MJF44I MJF45I			130 230		pF
Gain Bandwidth ProductMJF44I(I_C = 0.5 Adc, $V_{CE}$ = 10 Vdc, f = 20 MHz)MJF45IMJF45IMJF45I			50 40		MHz
SWITCHING TIMES					
Delay and Rise Times (I <sub>C</sub> = 5 Adc, I <sub>B1</sub> = 0.5 Adc) MJF45I MJF45I			300 135		ns
	ts	-	500 500		ns
Storage Time MJF44I   (I <sub>C</sub> = 5 Adc, I <sub>B1</sub> = I <sub>B2</sub> = 0.5 Adc) MJF45I   MJF45I MJF45I		-			



## MJF44H11 (NPN), MJF45H11 (PNP)

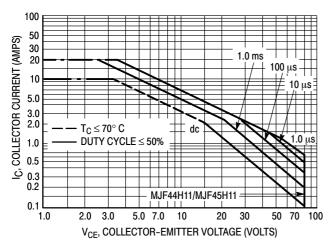
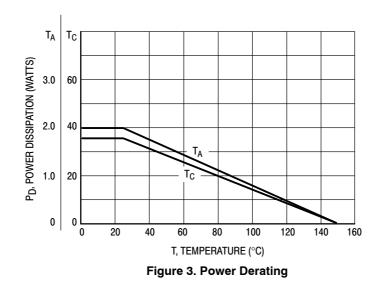


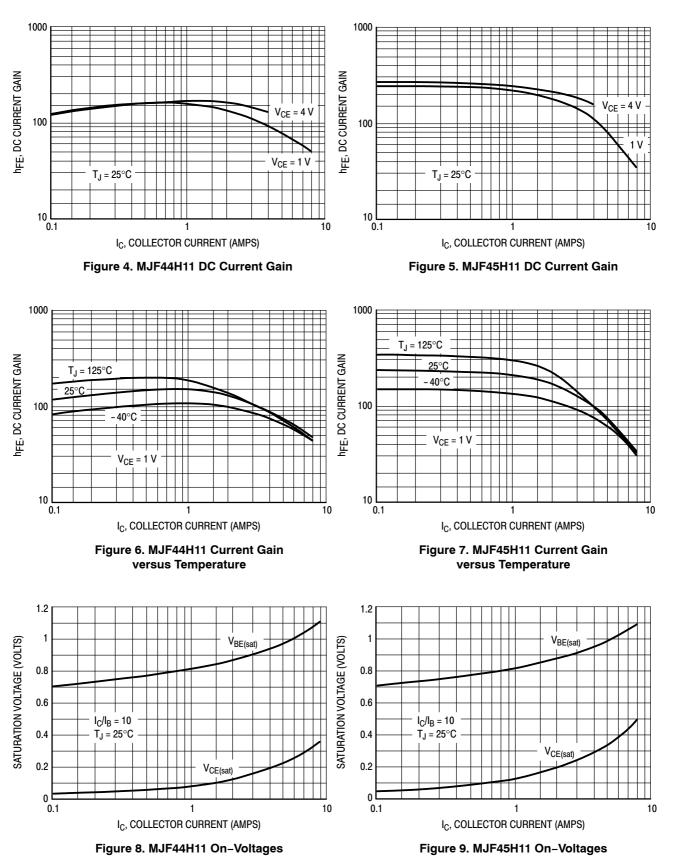
Figure 2. Maximum Rated Forward Bias Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

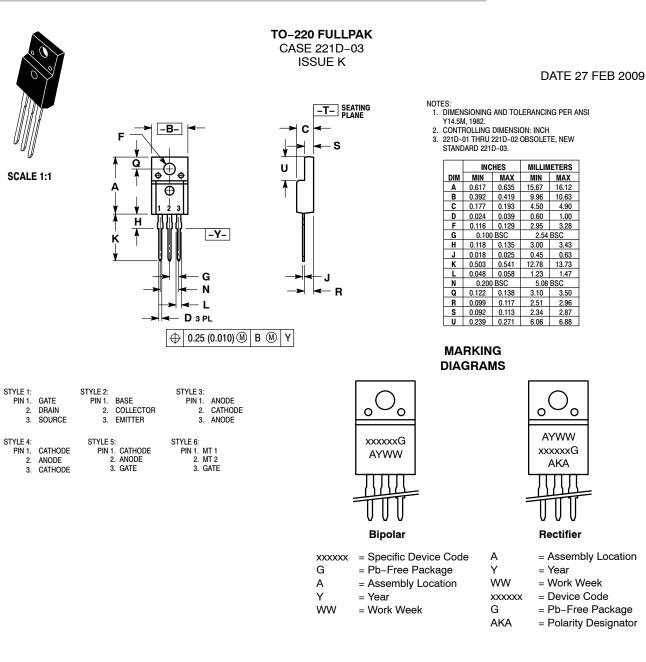
The data of Figure 2 is based on  $T_{J(pk)} = 150^{\circ}C$ ;  $T_C$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} \leq 150^{\circ}C$ .  $T_{J(pk)}$  may be calculated from the data in Figure 1. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.



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